

**COMBINED DECLARATION AND POWER OF ATTORNEY**

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE, the specification of which:

- is attached hereto.
- was filed on \_\_\_\_\_ as Application Serial No. \_\_\_\_\_ and was amended on \_\_\_\_\_.
- was described and claimed in PCT International Application No. \_\_\_\_\_ filed on \_\_\_\_\_ and as amended under PCT Article 19 on \_\_\_\_\_.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose all information I know to be material to patentability in accordance with Title 37, Code of Federal Regulations, §1.56.

I hereby claim the benefit under Title 35, United States Code, §119(e)(1) of any United States provisional application(s) listed below:

U.S. Serial No.	Filing Date	Status
-----------------	-------------	--------

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose all information I know to be material to patentability as defined in Title 37, Code of Federal Regulations, §1.56(a) which became available between the filing date of the prior application and the national or PCT international filing date of this application:

U.S. Serial No.	Filing Date	Status
-----------------	-------------	--------

I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate or of any PCT international application(s) designating at least one country other than the United States of America listed below and have also identified below any foreign application for patent or inventor's certificate or any PCT international application(s) designating at least one country other than the United States of America filed by me on the same subject matter having a filing date before that of the application(s) of which priority is claimed:

Country	Application No.	Filing Date	Priority Claimed
Japan	2000-244860	August 11, 2000	<input checked="" type="checkbox"/> Yes <input type="checkbox"/> No
Japan	2000-267851	September 4, 2000	<input checked="" type="checkbox"/> Yes <input type="checkbox"/> No

I hereby appoint the following attorneys and/or agents to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith:

John F. Hayden, Reg. No. 37,640; Scott C. Harris, Reg. No. 32,030; Michael McKeon, Reg. No. 37,888; Linda Liu Kordziel, Reg. No. 39,732; William E. Booth, Reg. No. 28,933; Ruffin B. Cordell, Reg. No. 33,487; John W. Freeman, Reg. No. 29,066; Timothy A. French, Reg. No. 30,175; G. Roger Lee, Reg. No. 28,963; Ralph A.

Combined Declaration and Power of Attorney

Page 2 of 2 Pages

Mittelberger, Reg. No. 33,195; John B. Pegram, Reg. No. 25,198; Rene D. Tegtmeier, Reg. No. 33,567; Charles C. Winchester, Reg. No. 21,040; William D. Hare, Reg. No. 44,739; James E. Mrose, Reg. No. 33,264; Lauren A. Degan, Reg. No. 40,584; Andrew F. Bodendorf, Reg. No. 39,537; Robert V. Racunas, Jr., Reg. No. 43,027; Diana DiBerardino, Reg. No. 45,653; W. Karl Renner, Reg. No. 41,265; Joseph F. Key, Reg. No. 44,827; Harold H. Fox, Reg. No. 41,498; Scott R. Boalick, Reg. No. 42,337; Joseph V. Colaianni, Jr., Reg. No. 39,948; Gregory A. Walters, Reg. No. 41,366; R. Whitney Winston, Reg. No. 44,432; Bing Ai, Reg. No. 43,312; N. Thane Bauz, Reg. No. 41,604; Robert Bedgood, Ph.D., Reg. No.43,488; Gregory P. Einhorn, Reg. No. 38,440; Diane L. Gardner, Reg. No. 36,518; James T. Hagler, Reg. No. 40,631; Kenyon S. Jenckes, Reg. No. 41,873; Samuel S. Lee, Reg. No. 42,791; Christopher S. Marchese, Reg. No. 37,177; Todd G. Miller, Reg. No. 42,003; Shekhar Vyas, Reg. No. 46,166; and John R. Wetherell, Jr., Ph.D., Reg. No. 31,678.

Address all telephone calls to John F. Hayden at telephone number (202) 783-5070.

Address all correspondence to John F. Hayden at:

FISH & RICHARDSON P.C.  
601 Thirteenth St., N.W.  
Washington, DC 20005

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patents issued thereon.

Full Name of Inventor: Hideto OHNUMA

Inventor's Signature: Hideto Ohnuma Date: 07/30/2001  
Residence Address: Kanagawa, Japan  
Citizenship: Japanese  
Post Office Address: C/O Semiconductor Energy Laboratory Co., Ltd.  
398, Hase, Atsugi-shi, Kanagawa-ken 243-0036 Japan

Full Name of Inventor: Ichiro UEHARA

Inventor's Signature: Ichiro Uehara Date: 07/30/2001  
Residence Address: Kanagawa, Japan  
Citizenship: Japanese  
Post Office Address: C/O Semiconductor Energy Laboratory Co., Ltd.  
398, Hase, Atsugi-shi, Kanagawa-ken 243-0036 Japan